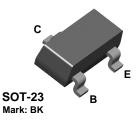


BCX71K



PNP General Purpose Amplifier

This device is designed for applications requiring extremely high current gain at collector currents to 300 mA. Sourced from Process 68.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	45	V
V _{CES}	Collector-Base Voltage	45	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	500	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 150 degrees C. 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units	
		*BCX71K		
PD	Total Device Dissipation	350	mW	
	Derate above 25°C	2.8	mW/°C	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	357	°C/W	

*Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

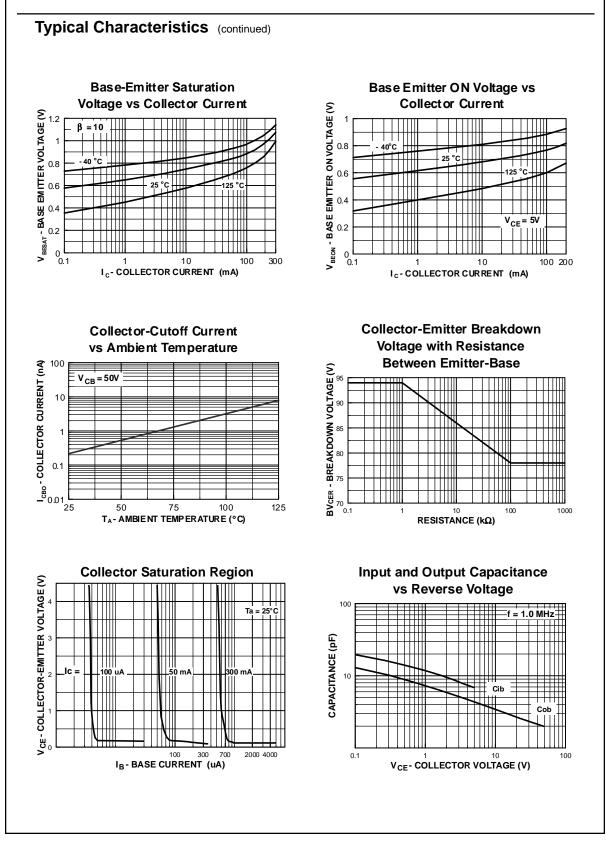
PNP General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Unit
		1 10	45		V
V _{(BR)CEO} V _{(BR)EBO}	Collector-Emitter Breakdown Voltage Emitter-Base Breakdown Voltage	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$ $I_{\rm E} = 10 \mu\text{A}, I_{\rm C} = 0$	45 5.0		V
V (BR)EBO	Collector-Cutoff Current	$V_{CB} = 45 \text{ V}, I_{E} = 0$	5.0	20	nA
CES		$V_{CB} = 45 \text{ V}, I_E = 0$ $V_{CB} = 45 \text{ V}, I_E = 0, T_A = 100^{\circ}\text{C}$		20	μA
ON CHAR	ACTERISTICS				
η _{FE}	DC Current Gain	$I_{C} = 10 \ \mu A, V_{CE} = 5.0 \ V$	100		
		$I_{C} = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	380	630	
1	Collector-Emitter Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, V_{\rm CE} = 1.0 \text{ V}$ $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.25 \text{ mA}$	110 0.06	0.25	V
/ _{CE(sat)}		$I_{\rm C} = 10$ mA, $I_{\rm B} = 0.25$ mA $I_{\rm C} = 50$ mA, $I_{\rm B} = 1.25$ mA	0.08	0.25	V
/ _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.25 \text{ mA}$	0.6	0.85	V
1	Base-Emitter On Voltage	$I_{C} = 50 \text{ mA}, I_{B} = 1.25 \text{ mA}$ $I_{C} = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	0.68 0.6	1.05 0.75	V
/ _{BE(on)}	Base Emilier on Voltage	$10 - 2.0$ m/t, $V_{CE} = 0.0$ V	0.0	0.70	v
SMALL SI	GNAL CHARACTERISTICS				
C _{obo}	Output Capacitance	$V_{CE} = 10 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$		6.0	pF
NF	Noise Figure	$I_{c} = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ V},$ $R_{s} = 2.0 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz},$ BW = 200 Hz		6.0	dB
SWITCHI	NG CHARACTERISTICS				
(on)	Turn-On Time	I _C = 10 mA, I _{B1} = 1.0 mA 150		ns	
(off)	Turn-Off Time	$I_{B2} = 1.0 \text{ mA}, V_{BB} = 3.6 \text{ V},$ R1 = R2 = 5.0 kΩ, R _L = 990 Ω		800	ns
Туріса	al Characteristics				
	Typical Pulsed Current Gain	Collector-I € Voltage vs			
NI 60 200 L	vs Collector Current				
NI GAIN					
000 0002 0002 0002 0002 0002 0002 0002	vs Collector Current				
D CURRENT GAIN	vs Collector Current				
1000 CURRENT GAIN	vs Collector Current				
PULSED CURRENT GAIN 000 000 000 000 000 000 000 000 000000	vs Collector Current				
1000 000 000 000 000 000 000 000 000 00	vs Collector Current				
177PICAL PULSED CURRENT GAIN	vs Collector Current				t
AL PULSED CURRENT C 000 000 000 000 000 000	vs Collector Current	E Voltage vs 0.3 0.3 β 0.3 β 0.25 β 10 0.15 0.15 0.15 0.1 0.05 0.1 0.1 1		or Curren	t

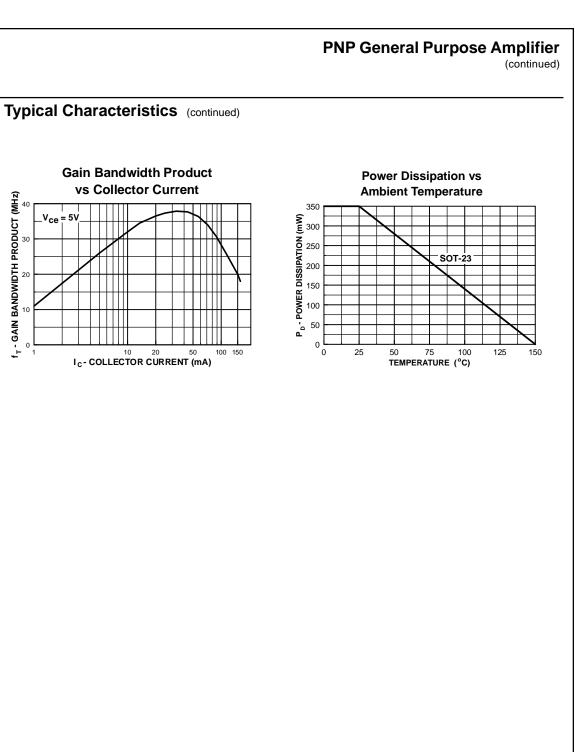
BCX71K

BCX71K

PNP General Purpose Amplifier (continued)



BCX71K



f_T - **GAIN BANDWIDTH PRODUCT (MHz)**

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